



WMP-SME-515

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By: MPZ

Date: 1/7/03

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Jenoe Tihanyi  
Applic. No. : 10/007,397  
Filed : October 22, 2001  
Title : Semiconductor Component  
Examiner : Monica Lewis  
Group Art Unit : 2822

A M E N D M E N T

Hon. Commissioner of Patents and Trademarks,  
Washington, D. C. 20231

S i r :

Responsive to the Office action dated September 30, 2002  
kindly amend the above-identified application as follows:

In the Translated Specification:

On page 8, lines 23-30, replace the paragraph with:

-- P-doped compensation zones 30 are formed in the n-doped layer 24 and, in the exemplary embodiment according to figure 1, extend in a pillar-shaped manner in the vertical direction

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